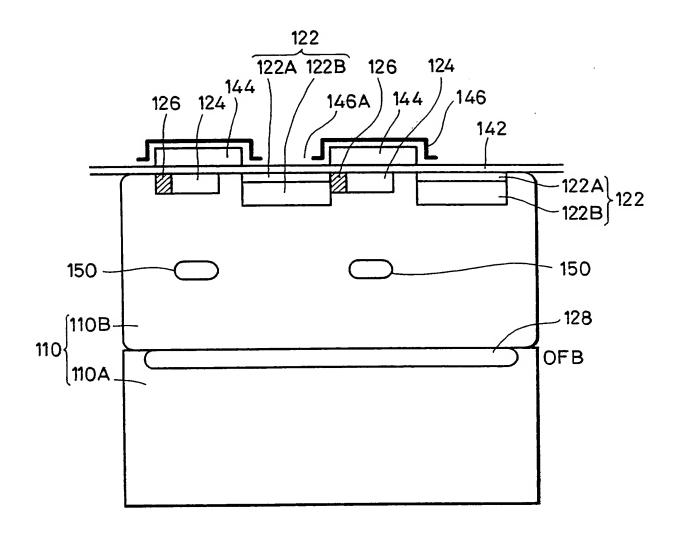
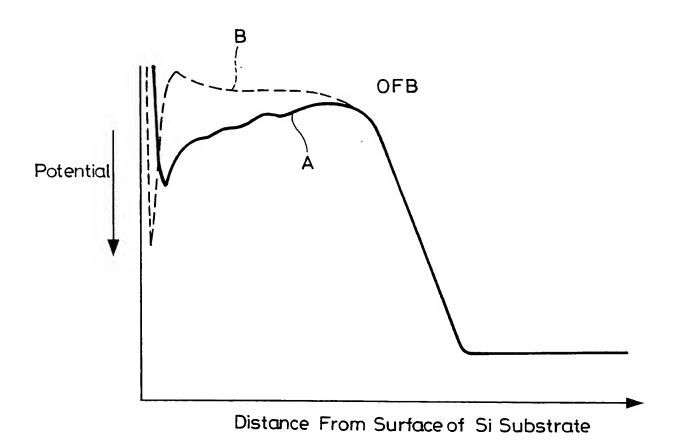
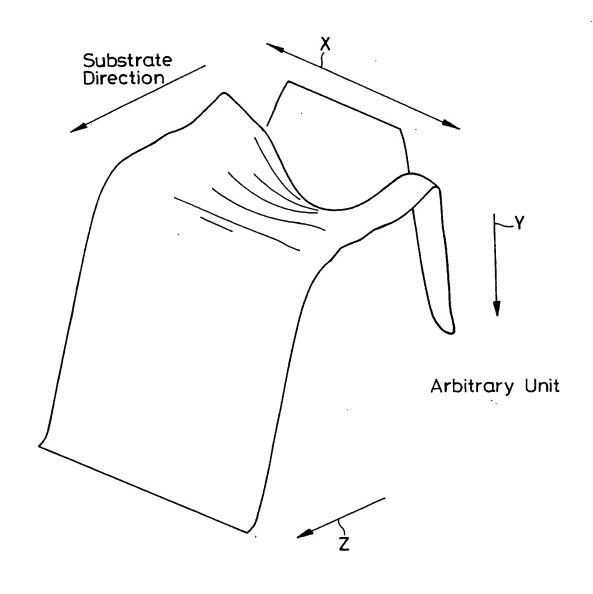
F/G. 1



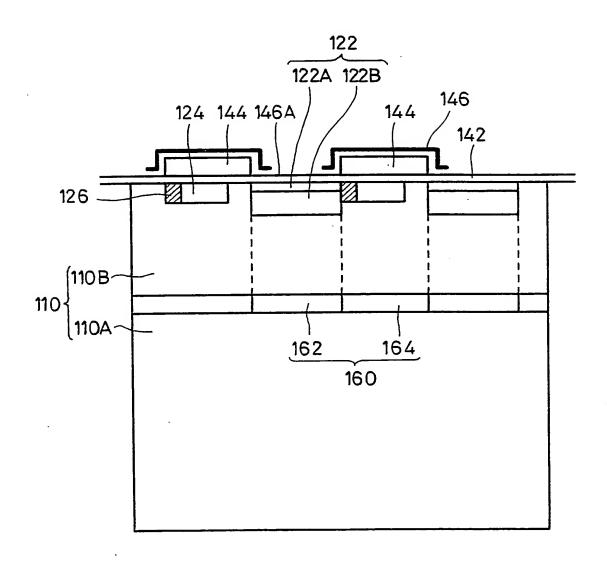
F1G. 2



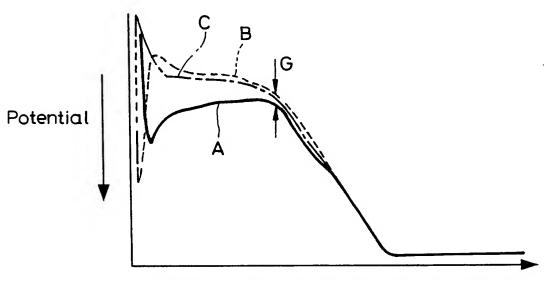
F1G. 3



F/G. 4



F/G. 5



Distance From Surface of Si Substrate

F/G. 6

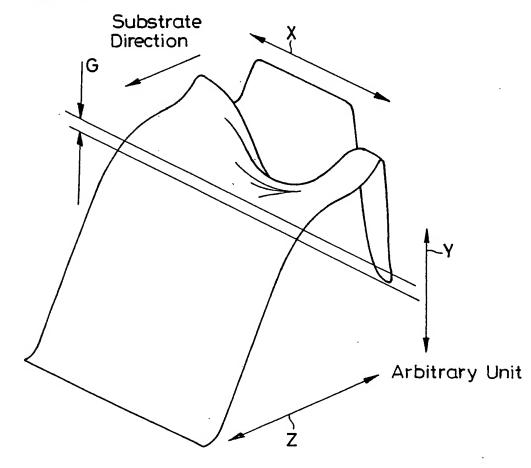


FIG. 7A

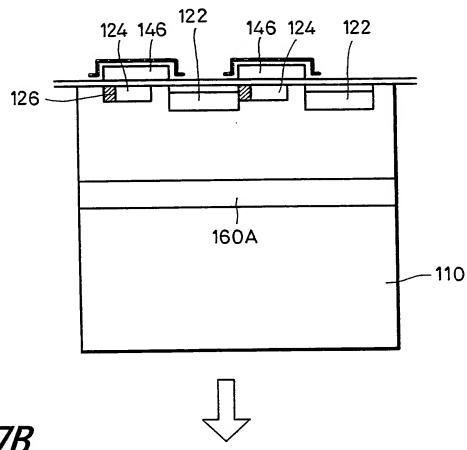


FIG. 7B

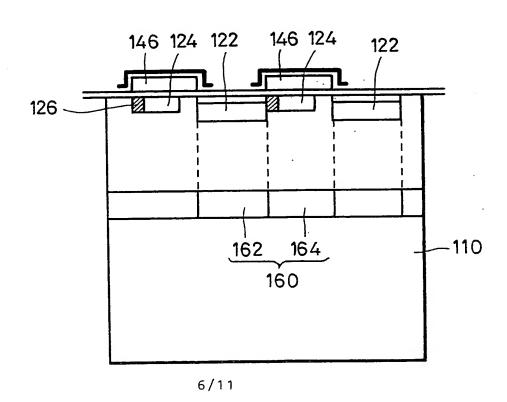


FIG. 8

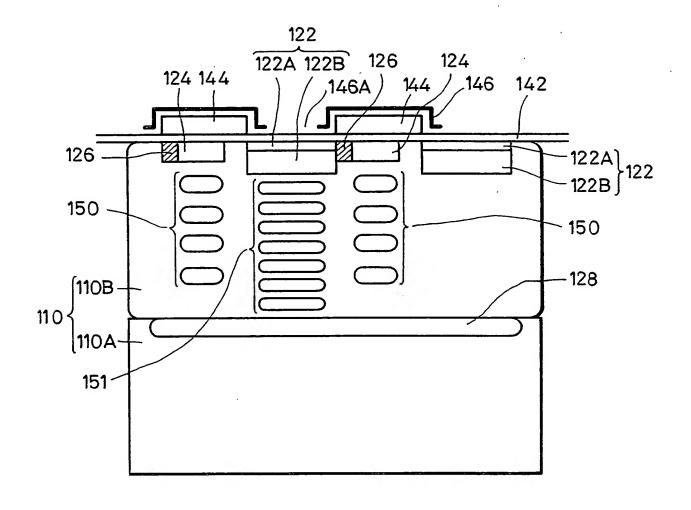
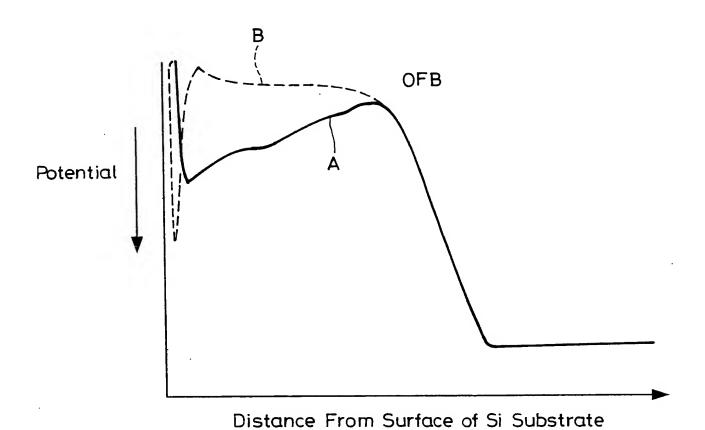


FIG. 9



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FIG. 10

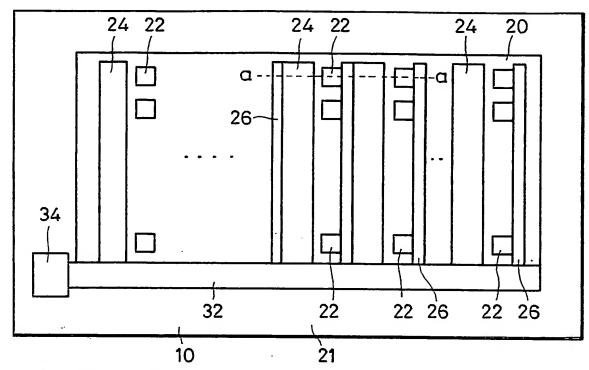


FIG. 11

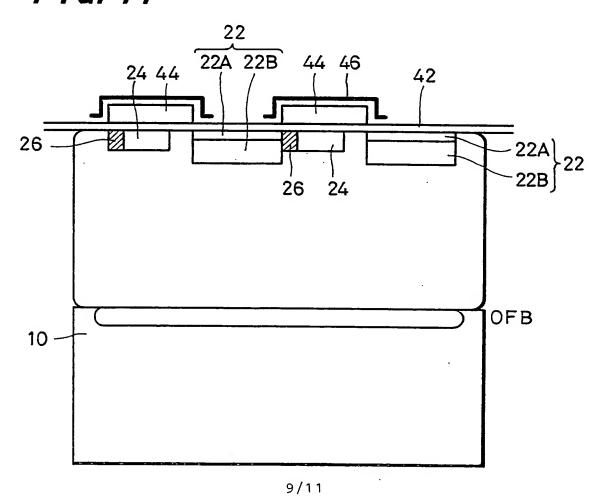


FIG. 12

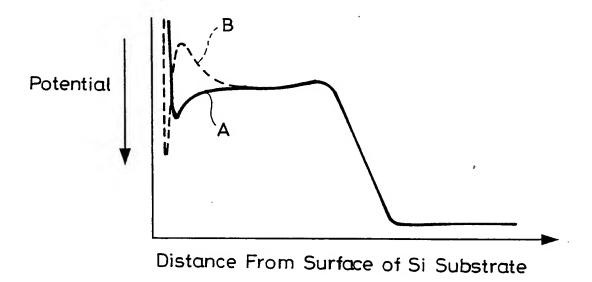
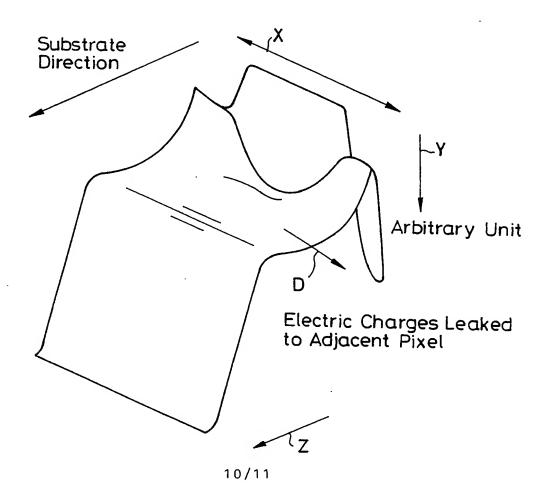


FIG. 13



## DESCRIPTION OF REFERENCE NUMERALS

110 ... semiconductor substrate

110A ... N type substrate

110B ... P type layer

122 ... photosensor

122A ... P<sup>+</sup> layer

122B ... N layer

124 ... vertical transfer register

126 ... channel stop region

128 ... overflow barrier

142 ... insulating film

144 ... transfer electrode

146 ... light-shielding film

150 ... P type region